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INFORMATI	ON DISCLO	SURE	Application Number	Unassigned	
STATEMENT BY APPLICANT			Filing Date	10/17/2005	(NOV 1 5 2005)
Data Submitted	l: November	15 2005	First Named Inventor	Tadahiro OHMI	2
Date Submitted: November 15, 2005			Group Art Unit	Unassigned	Way and
(use as many s	sheets as ne	cessary)	Examiner Name	Unassigned	TRADE
1	of	1	Attorney Docket Number	039262-0143	

				U.S. PATENT DOCUMENTS		
Examiner Initials*	Cite No.1	U.S. Patent Document			Date of Publication of	Pages, Columns, Lines, Where Relevant
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***************************************	B2	w. <u>SATOH</u> , et al., "Bapid Oxidation of SiC Using Microwave-Discharged 02 Plasma at Low Temperatures (<300°C)," Jap. J. of Applied Physics, Part 2, March 1, 2003, Vol. 41-3A, pp. L233-L235.	

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